

Ceramics Characteristics

Item	Unit	Material Testing Method	Oxide Ceramics					Non-Oxide Ceramics					Zero or less Thermal Expansion Ceramics			Machinable Ceramics	Other Normal Materials														
			Al ₂ O ₃					ZrO ₂	Si ₃ N ₄		SiC		AlN	ZPF	Adceram [®]		Macor [®]	Quartz	Sapphire	Si	Al (5012)	SUS (304)									
			A9951	A9951LD	A9951S	A9991	AHPF /AJPF	AYZ-3	ASN-4	SLPF	SiC	CLPF	AlN	N-Type	D1	D3															
Color	-	-	White	White	White	Milky White	White	White	Gray	Gray	Black	Black	Gray Beige	Gray	Light Yellow	White	White	Transparent	Transparent	-	-	-									
Bulk Density	(X10 ³)kg/m ³	Water displacement method	3.9	3.9	3.9	3.9	4.0	6.0	3.2	3.3	3.1	3.2	3.3	2.5	2.6	2.3	2.5	2.2	4	2.3	2.7	8.0									
Water Absorption Rate	%	Water displacement method	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	-	-	-									
Mechanical Feature	Hardness	Vickers	GPa	JIS R 1610	18	18	16	18	20	13	14	16	24	24	13	7	4.5	4.5	-	-	23	-	-	2							
	Bending Strength	20°C	MPa	JIS R 1601	450	350	220	480	550	1000	720	1000	500	500	350	250	200	150	130	50	700	-	-	300							
		1000°C	MPa	JIS R 1601	-	350	-	-	550	-	-	800	-	-	330	-	50	50	-	-	-	-	-	-							
		1200°C	MPa	JIS R 1601	300	200	170	300	400	350	400	-	600	600	250	-	-	-	-	-	-	-	-	-							
	Fracture Toughness		MPa√m	JIS R 1607	4	4	7	4	3	6	5	6	3	3	3	3	-	2	-	-	-	-	-	-							
	Young's Module		GPa	JIS R 1602	390	390	370	400	400	200	290	310	410	420	320	150	110	90	67	73	470	170	71	200							
Poisson's Ratio		K	JIS R 1602	0.24	0.24	0.24	0.24	0.24	0.32	0.28	0.24	0.16	0.16	0.29	0.28	0.25	0.25	0.29	0.17	-	-	-	-								
Thermal Feature	CTE	23±3°C	1/K(X10 ⁻⁶)	Laser coefficient of thermal expansion	5.3	-	-	-	-	-	-	1.4	-	2.3	-	0.0	-	-	-	-	-	-	-								
		25~200°C	1/K(X10 ⁻⁶)	JIS R 1618	5.4	5.6	5.7	5.3	5.6	7.7	1.7	1.7	2.9	2.8	2.4	-	-	-	-	7.2 (//C axle)	-	-	-								
		25~500°C	1/K(X10 ⁻⁶)	JIS R 1618	7.3	7.5	6.9	7.5	7.7	10.0	2.3	2.4	4.6	5.0	4.0	-	4.7 (~400°C)	0.9 (~400°C)	9.3 (~300°C)	0.5	-	-	-								
		25~1000°C	1/K(X10 ⁻⁶)	JIS R 1618	8.5	8.5	7.8	8.6	8.6	11.0	2.8	2.8	5.0	5.6	5.2	-	5.4 (~800°C)	1.4 (~800°C)	12.6 (~800°C)	-	-	-	-	17.3							
	Thermal Conductivity (20°C)		W/m·K	JIS R 1611	30	30	40	33	35	3	26	20	170	150	160	5	2.6	1.3	1.7	1	42	140	140	17							
Specific Heat		J/kg·K	JIS R 1611	800	800	840	800	800	470	630	650	660	660	740	1000	460	590	790	1050	-	690	-	880								
Thermal Fatigue (ΔT)		K	Water quenching method	200	200	500	200	200	280	700	800	450	450	400	-	350	700	150	-	-	-	-	-								
Corrosion Resistance	Chemical Resistance	Hydrochloric Acid (20%)	μm	Boiling 72hr	-0.3	-1.3	-0.6	-0.3	0.0	0.0	Erosion	Erosion	0.0	0.0	Erosion	-	-	-	0.0	-	-	-	-								
				Room Temp. 24hr	0.0	0.0	0.0	0.0	0.0	0.0	0.0	-0.1	-0.3	0.0	0.0	-0.6	-	-	-	-	-	-	-	-							
		Sulfuric Acid (20%)	μm	Boiling 72hr	-0.3	-1.3	-0.4	0.0	0.0	0.0	0.0	Erosion	Erosion	0.0	0.0	Erosion	-	-	-	-	-	-	-	-							
				Room Temp. 24hr	0.0	-0.3	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	-0.9	-	-	-	-	-	-	-	-							
		Nitric Acid (61%)	μm	Boiling 72hr	0.0	-0.5	-0.4	0.0	0.0	0.0	0.0	Erosion	Erosion	0.0	0.0	Erosion	-	-	-	-	-	-	-	-							
				Room Temp. 24hr	0.0	0.0	0.0	0.0	0.0	0.0	0.0	-0.2	-0.6	0.0	0.0	-0.6	-	-	-	-	-	-	-	-							
		Phosphoric Acid (85%)	μm	Boiling 72hr	Erosion	Erosion	Erosion	-0.3	0.0	-3.2	Erosion	-2.1	0.0	0.0	Erosion	-	-	-	-	-	-	-	-	-							
				Room Temp. 24hr	-2.8	0.0	0.0	-0.3	0.0	0.0	0.0	0.0	0.0	0.0	0.0	-1.8	-	-	-	-	-	-	-	-							
Sodium hydroxide (20%)	μm	Boiling 72hr	0.0	-0.5	0.0	0.0	0.0	0.0	0.0	-1.1	0.0	0.0	0.0	Erosion	-	-	-	-	-	-	-	-									
		Room Temp. 24hr	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.0	-1.5	-	-	-	-	-	-	-	-									
HF(47%)	μm	20°C 72hr	0.0	Erosion	-0.2	0.0	0.0	Erosion	-3.3	-2.4	0.0	0.0	-3.6	-	-	-	-	-	-	-	-	-									
Electronic Feature	Insulation Strength		kV/mm	Bias voltage applied LB technique	12	12	-	12	12	>10	>10	>10	-	-	>15	-	20	20	40	>10	>30	-	-								
	Volume Resistivity (20°C)		Ω·cm	3 probes method	>10 ¹⁴	>10 ¹⁴	>10 ¹⁴	>10 ¹⁴	>10 ¹⁴	10 ¹²	>10 ¹⁴	>10 ¹⁴	10 ⁶	10 ⁶	10 ¹⁴	10 ¹²	10 ¹²	10 ¹⁰	10 ¹⁶	>10 ¹⁴	>10 ¹⁴	-	-								
	Dielectric constant (25°C)	1MHz	-	Bridge method	10	10	10	10	10	35	8	8	-	-	9	-	7.5	7.5	6	4	11.5 (//C axle)	-	-								
		3GHz	-	Dielectric resonator method	10	10	10	10	10	40	8	8	-	-	8	-	-	-	-	-	-	-	-								
	Dielectric Loss (25°C)	1MHz	X10 ⁻⁴	Voltammeter method	30	3	4	7	1	20	3	10	-	-	10	-	35	35	5	1	-	-	-								
3GHz		X10 ⁻⁴	Dielectric resonator method	4	1	4	-	<1	10	90	10	-	-	130	-	-	-	-	-	<1	-	-									
Abrasion performance (Blast abrasion loss)		μm	30°, 5.5kg/cm ² , 2min.	2.1	2.3	-	1.0	0.8	0.5	-	0.3	1.6	1.3	-	1.2	-	-	-	-	-	-	-									
Relative Magnetic Permeability		-	-	1.0000	-	-	-	-	-	-	1.0000	1.0002	1.0000	-	1.0000	-	-	-	-	-	-	-									
Feature			Possible for huge size, Relatively-low cost					Low dielectric constant, Possible for huge size, Relatively-low cost		High fracture toughness, High thermal shock resistance, Low dielectric constant, Possible for huge size, Relatively-low cost		Possible for huge size		Pore free (Dense), Low chemical resistance, Low dielectric constant		High strength, High fracture toughness, Low thermal conductivity, High wear resistance		High fracture toughness, Low thermal expansion, High thermal shock resistance, High wear resistance		High hardness, High stiffness, High thermal conductivity, High chemical resistance		High thermal conductivity, High plasma resistance, Suitable for ESC		Zero thermal expansion, High stiffness comparing to glass material, Pore free, Suitable for ESC		Low thermal expansion, High thermal shock resistance		High strength comparing to glass material, Low thermal conductivity		Short lead-time, High machinability, High electric insulation, Low thermal conductivity	